

Improving Probe-Tip S-parameters Measurements with Power Calibrations

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Agenda

- Market Trends
- Quick Recap of S-parameters Measurements
- Current Practices for Wafer-level RF Measurements & Challenges
- Proposed Probe-tip S-parameter + Power calibration
- Summary



Market Trends

- 5G will dominate RF device growth
 - Not just for mobile comms but for
 - IoT, eHealth, Transportation, Industrial Machine Control & more
 - Higher Operating Frequencies
 - 28 to 73 GHz
 - 个 New 110 GHz Systems around the world
 - Important & Urgent to address
 Challenges in testing RF devices at these frequencies.

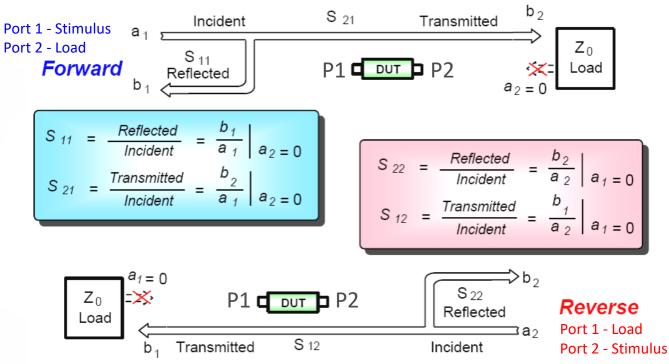
5G 2020 Very High Data rate Very High Capacity Reliable & Secure Huge no. of Devices Long Battery Life Very Low latency ... Everything Everywhere Connected



⁵G mobile wireless - Hugh Nicklin



Quick Recap of S-parameters Measurements



S-parameters are relative and not absolute measurements!





Current Practices for Wafer-level RF Measurements & Challenges

Only Adopts S-parameter calibration

- Since S-parameters are relative measurements, Probe-tip power calibration is redundant – or so we thought?

Uncalibrated RF Source Power – Affects Accuracy

- Large RF power, Stable Cal but Active Device's DC bias condition would be incorrect
- Small RF power, Difficult to get a stable calibration
- ⇒ Need to Optimize RF power & make it Constant w.r.t. Frequency

Post-Calibration Stability – How long a calibration state can lasts?

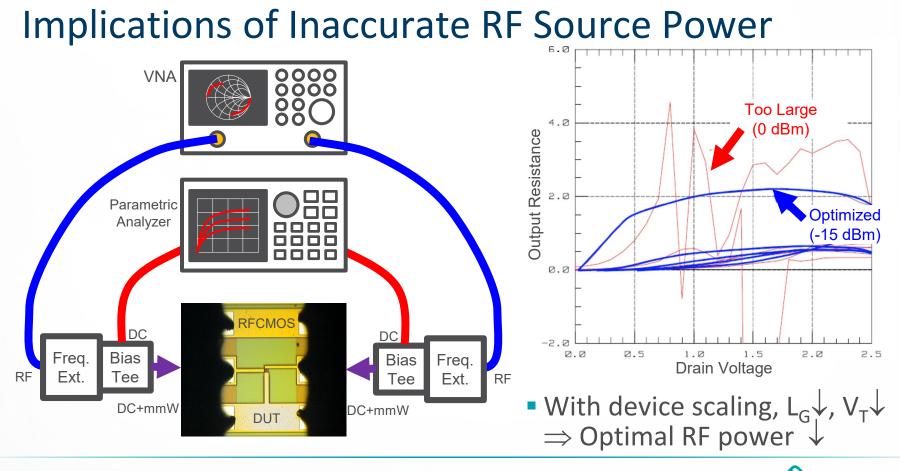
- Affects Accuracy & Measurement Throughput
- Environment & Cable lengths are often assumed to be primary root cause
 - Control Lab temperature/Humidity
 - Use Shortest cable possible
- Optimizing VNA instrument settings eg Low IFBW of 5 Hz



Typical Single Sweep 110 GHz Probe System Setup



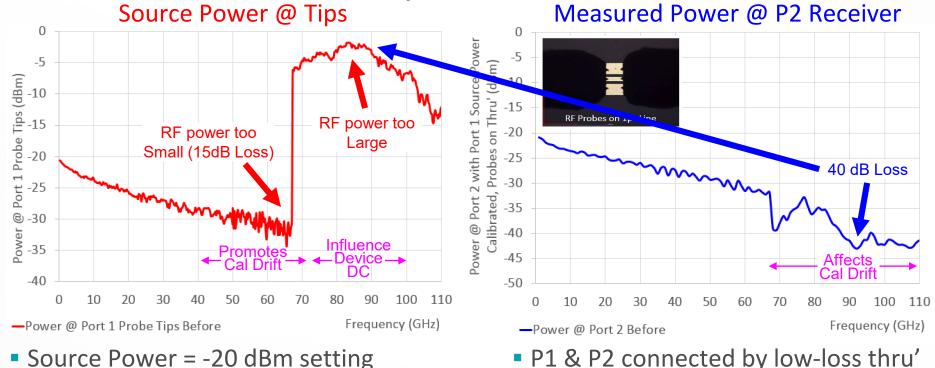






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Uncalibrated Probe Tip RF Source Power



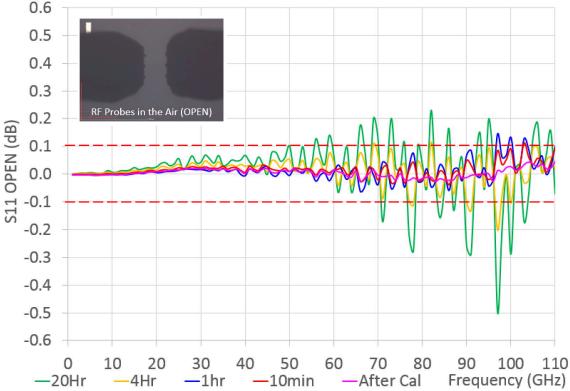
Source Power = -20 dBm setting
Power should be constant w.r.t freq.

P2 should detect -20 dBm



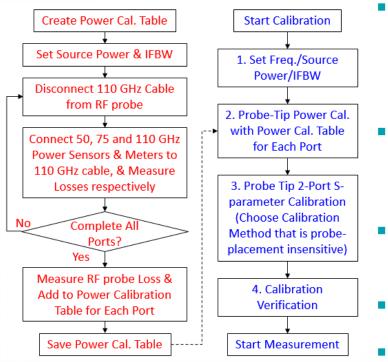
Post-Calibration Stability (No Tip Power Cal)

- Probes in Air as OPEN, Source power = -20dBm, IFBW = 10 Hz, LRRM cal.
- ±0.1dB as criteria, Cal. only last 10 mins
- Test engineers need to recalibrate every 10 mins
 - Passive devices take 1 min
 - RFCMOS device requires about 30 mins to measure





Probe-Tip Power+S-parameter Cal.

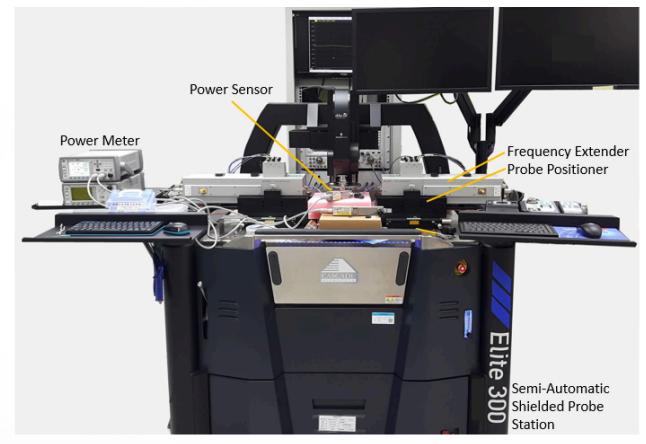


Create Power Table (one time pain)

- Characterize losses to the cables
- Extend losses to the RF probe tips
- Table is reusable unless setup modifications
- Wafer-Level Power+S-parameter Calibration
 - Perform Power cal. with power table
 - Perform standard S-parameters cal.
- No removal/installation of RF cables/probes during calibration
- Simple & Convenient
- Takes about 10% more time to complete Cal.

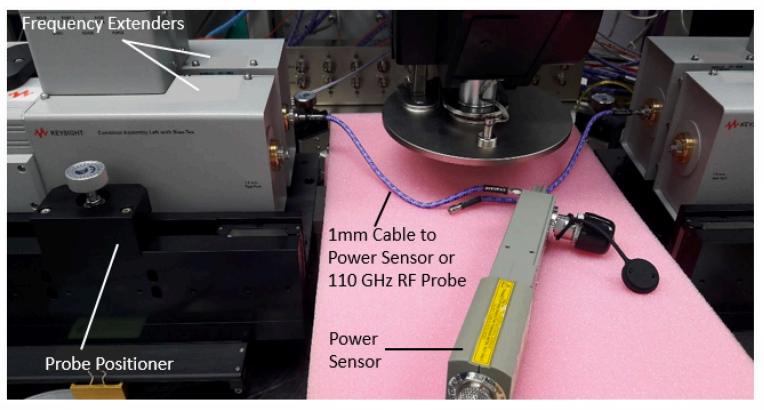


Creating Power Table for Power Calibration





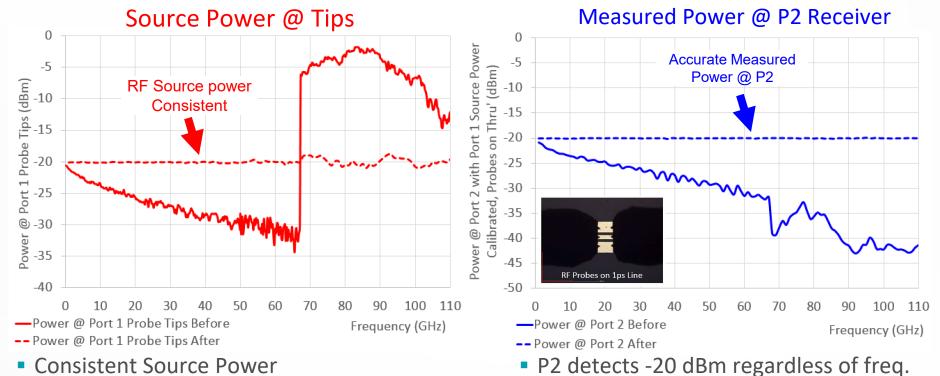
Creating Power Table for Power Calibration



Measuring Actual Power at the 1mm cable

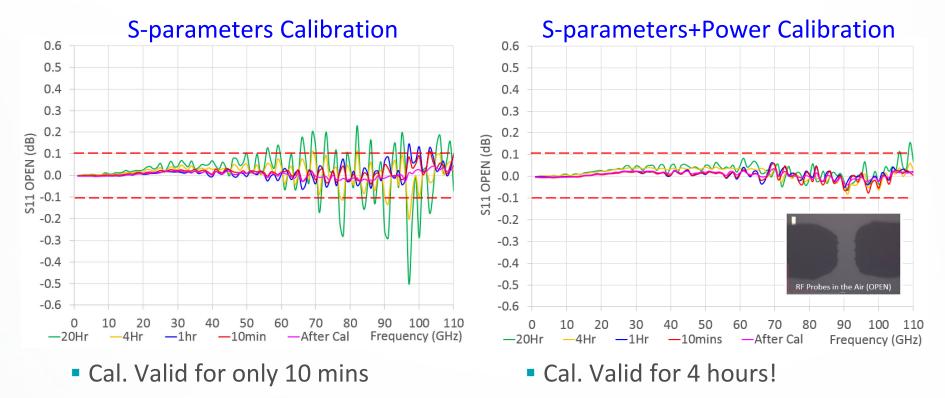


RF Power @ Probe Tips after Power Calibration



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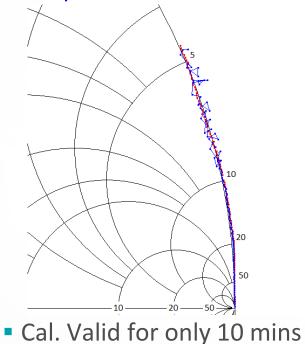
Probes in Air - Calibration Drift over 20 Hours



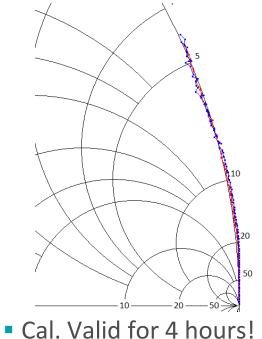


Probes in Air - Calibration Drift over 20 Hours

S-parameters Calibration



S-parameters+Power Calibration





Summary

- Power Calibration is Critical even though S-parameters is a relative and not absolute measurement!
- Adopting Power+S-parameters Probe Tip Calibration takes 10% more time but will...
 - Ensure Accurate RF source power is applied to Active Devices
 - Improve Calibration Stability to more than 4 Hours
 - Maximize Test Throughput

